	Type	Hits	Search Text	DBs
1	BRS	757	361/93.1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
2	BRS	4442	current adj (sense sensing) adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
3	BRS	178	current adj (sense sensing) near (MOS MOSFET FET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
4	BRS	0	current adj (sense sensing) near (MOS MOSFET FET field adj effect) near switch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
5	BRS	36	current adj (sense sensing) near (MOS MOSFET FET field adj effect) same switch	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
6	BRS	4	5,986,441	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
7	BRS	5	("4914542" | "5004970" | "5008586" | "5164659" | "5220207").PN.	USPAT
8	BRS	10	5,805,434	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
9	BRS	3	6,282,107	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
10	BRS	12	("4975821" | "5126931" | "5331533" | "5374857" | "5434768" | "5734563" | "5774350" | "5805434" | "5812383" | "5814884" | "5886383" | "5973939").PN.	USPAT
11	BRS	12	("4975821" | "5126931" | "5331533" | "5374857" | "5434768" | "5734563" | "5774350" | "5805434" | "5812383" | "5814884" | "5886383" | "5973939").PN.	USPAT
12	BRS	12	("4975821" | "5126931" | "5331533" | "5374857" | "5434768" | "5734563" | "5774350" | "5805434" | "5812383" | "5814884" | "5886383" | "5973939").PN.	USPAT
13	BRS	2179645	current adj (sense sensing) near across (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
14	BRS	3	current adj (sense sensing) near across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
1	2004/09/01 09:30			0
2	2004/08/31 09:21			0
3	2004/08/31 09:22			0
4	2004/08/31 09:23			0
5	2004/08/31 11:29			0
6	2004/08/31 11:24			0
7	2004/08/31 11:15			0
8	2004/08/31 11:26			0
9	2004/08/31 11:28			0
10	2004/08/31 11:26			0
11	2004/08/31 11:27			0
12	2004/08/31 11:27			0
13	2004/08/31 11:30			0
14	2004/08/31 11:42			0

	Type	Hits	Search Text	DBs
15	BRS	14	over adj current same voltage adj across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
16	BRS	14	over adj current same voltage near across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
17	BRS	5	("4479083" | "4502000" | "4502001" | "4949028" | "4967136").PN.	USPAT
18	BRS	22	5528122.URPN.	USPAT
19	BRS	22	5528122.URPN.	USPAT
20	BRS	130	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
21	BRS	92	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) and temperature	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
22	BRS	11	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) same temperature	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
23	BRS	5	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) and temperature adj (sense sensing)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
24	BRS	1	over adj current and voltage near across adj (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
25	BRS	4	("5530335" | "5554919" | "5721480" | "5736832").PN.	USPAT
26	BRS	3	6014030.URPN.	USPAT
27	BRS	3	6014030.URPN.	USPAT
28	BRS	5	over adj current and voltage near (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
29	BRS	106644	voltage adj across (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
15	2004/08/31 12:07			0
16	2004/08/31 12:11			0
17	2004/08/31 12:09			0
18	2004/08/31 12:10			0
19	2004/08/31 12:10			0
20	2004/08/31 12:11			0
21	2004/08/31 12:12			0
22	2004/08/31 12:27			0
23	2004/08/31 12:35			0
24	2004/08/31 13:15			0
25	2004/08/31 12:54			0
26	2004/08/31 12:56			0
27	2004/08/31 12:56			0
28	2004/08/31 13:34			0
29	2004/08/31 13:34			0

	Type	Hits	Search Text	DBs
30	BRS	14	voltage adj across adj (MOS MOSFET FET field adj effect switch) and temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
31	BRS	0	voltage adj across adj (MOS MOSFET FET field adj effect switch) same temperature adj (compensating compensate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
32	BRS	502	temperature adj (compensate compensating) adj resistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
33	BRS	0	temperature adj (compensate compensating) adj resistor same operational adj amplifier same voltage adj drop near (MOS FET MOSFET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
34	BRS	0	temperature adj (compensate compensating) adj resistor same voltage adj drop near (MOS FET MOSFET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
35	BRS	0	temperature adj (compensate compensating) adj resistor and voltage adj drop near (MOS FET MOSFET field adj effect)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
36	BRS	40	temperature adj (compensate compensating) adj resistor same operational adj amplifier	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
37	BRS	17	temperature adj (compensate compensating) adj resistor same current adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
38	BRS	20	temperature adj (compensate compensating) near resistor same current adj source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
39	BRS	354	324/705	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
40	BRS	6	6,014,030	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
41	BRS	929	324/713	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB

	Time Stamp	Comments	Error Definition	Errors
30	2004/08/31 13:37			0
31	2004/08/31 13:38			0
32	2004/08/31 13:39			0
33	2004/08/31 13:40			0
34	2004/08/31 13:40			0
35	2004/08/31 13:41			0
36	2004/08/31 15:57			0
37	2004/08/31 16:03			0
38	2004/08/31 16:25			0
39	2004/08/31 16:25			0
40	2004/09/01 10:25			0
41	2004/09/01 10:32			0